

## **Inverting Charge Pump Voltage Doublers with Active High Shutdown**

#### **Features**

- Small 8-Pin MSOP Package
- Operates from 1.8V to 5.5V
- 120 Ohms (typ) Output Resistance
- 99% Voltage Conversion Efficiency
- Only 3 External Capacitors Required
- · Power-Saving Shutdown Mode
- Low Active Supply Current
  - 95μA (typ) for TC1682
  - 225μA (typ) for TC1683
  - 700μA (typ) for TC1684
- Fully Compatible with 1.8V Logic Systems

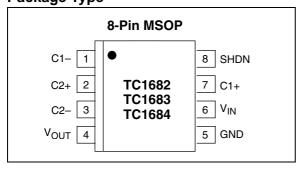
### **Applications**

- LCD Panel Bias
- · Cellular Phones PA Bias
- Pagers
- · PDAs, Portable Data Loggers
- Battery-Powered Devices

#### **Device Selection Table**

Part Number	Package	Osc. Freq. (kHz)	Operating Temp. Range
TC1682EUA	8-Pin MSOP	12	-40°C to +85°C
TC1683EUA	8-Pin MSOP	35	-40°C to +85°C
TC1684EUA	8-Pin MSOP	125	-40°C to +85°C

## Package Type



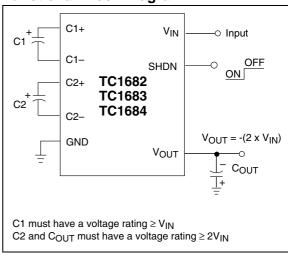
### **General Description**

The TC1682/TC1683/TC1684 are CMOS charge pump converters that provide an inverted doubled output from a single positive supply. An on-board oscillator provides the clock and only three external capacitors are required for full circuit implementation. Switching frequencies are 12kHz for the TC1682, 35kHz for the TC1683, and 125kHz for the TC1684. When the SHDN pin is held at a logic high, the device goes into a very low power mode of operation consuming less than  $1\mu A$  (typ) of supply current.

Low output source impedance (typically  $120\Omega$ ), provides output current up to 10mA. The TC1682/TC1683/TC1684 feature a 1.8V to 5.5V operating voltage range and high efficiency, which make them an ideal choice for a wide variety of applications requiring a negative doubled voltage derived from a single positive supply (for example: generation of -7.2V from a +3.6V lithium cell or -10V generated from a +5V logic supply).

The minimum external part count, small physical size and shutdown mode feature make this family of products useful for a wide variety of negative bias power supply applications.

### **Functional Block Diagram**



# 1.0 ELECTRICAL CHARACTERISTICS

## **Absolute Maximum Ratings\***

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\*Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions above those indicated in the operation sections of the specifications is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

#### TC1682/TC1683/TC1684 ELECTRICAL SPECIFICATIONS

Electrical Characteristics:  $T_A = -40^{\circ}C$  to  $+85^{\circ}C$ ,  $V_{IN} = +5V$ ,  $C1 = C2 = 3.3\mu F$  (TC1682),  $C1 = C2 = 1\mu F$  (TC1683),  $C1 = C2 = 0.33\mu F$  (TC1684). SHDN = GND. Typical values are at  $T_A = +25^{\circ}C$ 

	C1 = C2 = $0.33\mu\text{F}$ (TC1684), SHDN = GND, Typical values are at $T_A$ = +25°C						
Symbol	Parameter	Min	Тур	Max	Units	Device	Test Conditions
I <sub>DD</sub>	Supply Current	_	95	160	μΑ	TC1682	
		_	225	480		TC1683	5
		_	700	1500	700	TC1684	
I <sub>SHDN</sub>	Shutdown Supply Current	_	0.5	2	μΑ	All	SHDN = V <sub>IN</sub> = +5V
V <sub>MIN</sub>	Minimum Supply Voltage	1.8	_	-/	V	All	$R_{LOAD} = 1k\Omega$
V <sub>MAX</sub>	Maximum Supply Voltage	_	4	5.5	V	All	$R_{LOAD} = 1k\Omega$
Fosc	Oscillator Frequency	8.4	12	15.6	kHz	TC1682	
		24.5	35	45.5	*	TC1683	
		65	125	170		TC1684	
V <sub>IH</sub>	SHDN Input Logic High	1.4	7	_	V	All	$V_{IN} = V_{MIN}$ to $V_{MAX}$
$V_{IL}$	SHDN Input Logic Low			0.4	V	All	$V_{IN} = V_{MIN}$ to $V_{MAX}$
V <sub>EFF</sub>	Voltage Conversion Efficiency	95	99	_	%	All	R <sub>LOAD</sub> = ∞
R <sub>OUT</sub>	Output Resistance	_	120	170	Ω	All	I <sub>LOAD</sub> = 0.5mA to 10mA (Note 1)
T <sub>WK</sub>	Wake-up Time From Shutdown Mode	_	1800	_	μsec	TC1682	$R_{LOAD} = 2k\Omega$
		_	600	_		TC1683	
		_	200	_		TC1684	

Note 1: Capacitor contribution is approximately 20% of the output impedance (ESR = 1/ pump frequency x capacitance).

## 2.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 2-1.

TABLE 2-1: PIN FUNCTION TABLE

Pin No. (8-Pin MSOP)	Symbol	Description	
1	C1-	C1 commutation capacitor negative terminal.	
2	C2+	C2 commutation capacitor positive terminal.	
3	C2-	C2 commutation capacitor negative terminal.	
4	V <sub>OUT</sub>	Doubling inverting charge pump output (-2 x V <sub>IN</sub> ).	
5	GND	Ground.	
6	V <sub>IN</sub>	Positive power supply input.	
7	C1+	C1 commutation capacitor positive terminal.	
8	SHDN	Shutdown input (active high).	



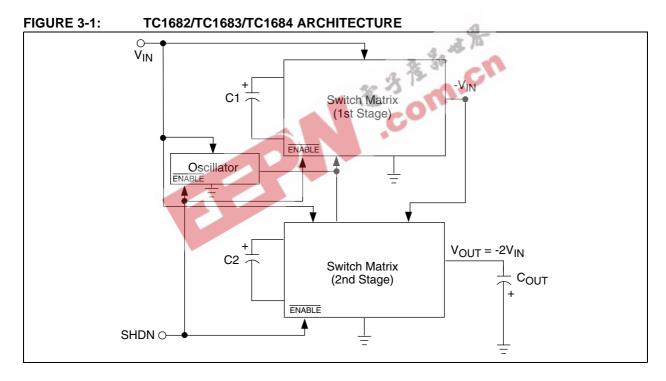
## 3.0 DETAILED DESCRIPTION

The TC1682/TC1683/TC1684 inverting charge pump converters perform a -2x multiplication of the voltage applied to the  $V_{\text{IN}}$  pin. Conversion is performed using two *synchronous* switching matrices and three external capacitors. When the shutdown input is held at a logic high, the device goes into a very low power mode of operation consuming less than  $1\mu\text{A}$  of supply current.

Figure 3-1 is a block diagram representation of the TC1682/TC1683/TC1684 architecture. The first switching stage inverts the voltage present at  $V_{IN}$  and the second stage uses the '- $V_{IN}$ ' output generated from the first stage to produce the '-2X' output function from the second stage switching matrix.

Each device contains an on-board oscillator that synchronously controls the operation of the charge pump switching matrices. The TC1682 synchronously switches at 12kHz, the TC1683 synchronously switches at 35kHz, and the TC1684 synchronously switches at 125kHz. The different oscillator frequencies for this device family allow the user to trade-off capacitor size versus supply current. Faster oscillators can use smaller external capacitors, but will consume more supply current (see Section 1.0 Electrical Characteristics).

When the shutdown input is in a high state, the oscillator and both switch matrices are powered off placing the TC1682/TC1683/TC1684 in the shutdown mode. When the  $V_{\rm IN}$  supply input is powered from an external battery, the shutdown mode minimizes power consumption, which in turn will extend the life of the battery.



## 4.0 APPLICATIONS INFORMATION

## 4.1 Output Voltage Considerations

The TC1682/TC1683/TC1684 perform inverting voltage conversions but do not provide any type of regulation. The output voltage will droop in a linear manner with respect to the output load current. The value of the equivalent output resistance is approximately 120 $\Omega$  nominal at +25°C and V<sub>IN</sub> = +5V. In this particular case, the output is approximately -10V at very light loads and will droop according to the equation below:

 $V_{DROOP} = I_{OUT} \times R_{OUT}$ 

## 4.2 Capacitor Selection

In order to maintain the lowest output resistance and output ripple voltage, it is recommended that low ESR capacitors be used. Additionally, larger values of C1 and C2 will lower the output resistance and larger values of  $C_{OLT}$  will reduce output ripple.

**Note:** For proper charge pump operation, C1 must have a voltage rating greater than or equal to V<sub>IN</sub>, while C2 and C<sub>OUT</sub> must have a voltage rating greater than or equal to

Table 4-1 shows various values of C1/C2 and the corresponding output resistance values for  $V_{IN} = 5V$  @ +25°C.

Table 4-2 shows the output voltage ripple for various values of  $C_{OUT}$  (again assuming  $V_{IN} = 5V$  @ +25°C). The  $V_{RIPPLE}$  values assume a 1mA output load current and a  $0.1\Omega$  ESR<sub>COUT</sub>.

TABLE 4-1: OUTPUT RESISTANCE VS. C1/C2 (ESR =  $0.1\Omega$ )

C1, C2 (μF)	TC1682 R <sub>OUT</sub> (Ω)	TC1683 R <sub>OUT</sub> (Ω)	TC1684 R <sub>OUT</sub> (Ω)
0.33	633	184	120
1	262	120	102
3.3	120	95	84

TABLE 4-2: OUTPUT VOLTAGE RIPPLE VS.  $C_{OUT2}$  (ESR = 0.1 $\Omega$ )  $I_{OUT}$  = 1mA

C <sub>OUT</sub> (μF)	TC1682 V <sub>RIPPLE</sub> (mV)	TC1683 V <sub>RIPPLE</sub> (mV)	TC1684 V <sub>RIPPLE</sub> (mV)
0.33	192	60	27
1	63	21	16
3.3	17	8	7

## 4.3 Input Supply Bypassing

The  $V_{IN}$  input should be capacitively bypassed to reduce AC impedance and minimize noise effects due to the switching internal to the device. It is recommended that a large value capacitor (at least equal to C1) be connected from  $V_{IN}$  to GND for optimal circuit performance.

## 4.4 Shutdown Input

The TC1682/TC1683/TC1684 is enabled when SHDN is low, and disabled when SHDN is high. This input cannot be allowed to float. (If SHDN is not required, see the TC2682/TC2683/TC2684 data sheet.) The SHDN input should be limited to 0.3V above  $V_{\text{IN}}$ .

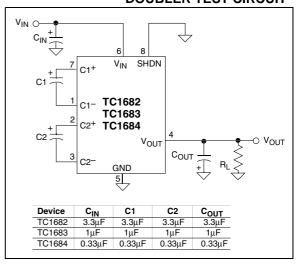
## 4.5 Inverting Voltage Doubler

The most common application for the TC1682/TC1683/TC1684 devices is the inverting voltage doubler (Figure 4-1). This application uses three external capacitors: C1, C2 and  $C_{OUT}$ .

Note: A power supply bypass capacitor is recommended.

The output is equal to -2V<sub>IN</sub> plus any voltage drops due to loading. Refer to Table 4-1 and Table 4-2 for capacitor selection guidelines.

FIGURE 4-1: INVERTING VOLTAGE DOUBLER TEST CIRCUIT



#### 4.6 Layout Considerations

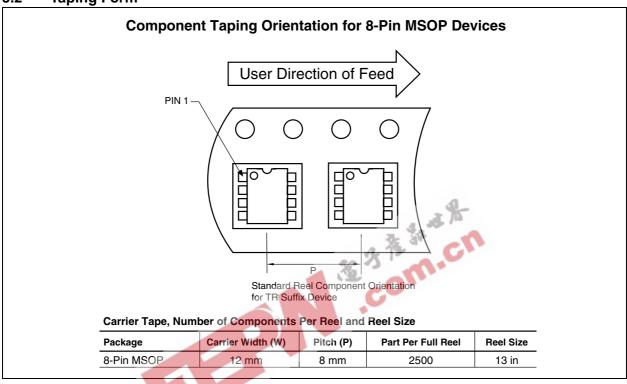
As with any switching power supply circuit, good layout practice is recommended. Mount components as close together as possible to minimize stray inductance and capacitance. Also use a large ground plane to minimize noise leakage into other circuitry.

## 5.0 PACKAGING INFORMATION

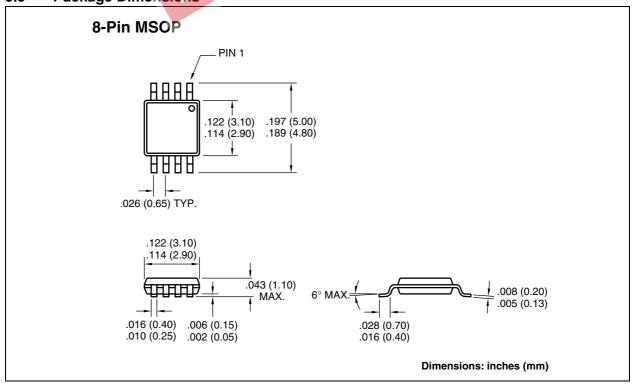
## 5.1 Package Marking Information

Package marking data not available at this time.

## 5.2 Taping Form



## 5.3 Package Dimensions



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